HALOGEN

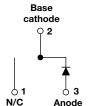
FREE



Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 15 A





PRODUCT SUMMARY						
V_{R}	600 V					
V _F at 15 A at 25 °C	1.7 V					
I _{F(AV)}	15 A					
t _{rr} (typical)	23 ns					
T _J (maximum)	150 °C					
Q _{rr}	84 nC					
dI _{(rec)M} /dt	188 A/μs					

FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- · Specified at operating conditions
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified

BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA15TB60S is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 15 A continuous current, the VS-HFA15TB60S is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA15TB60S is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	V_R		600	V		
Maximum continuous forward current	I _F	T _C = 100 °C	15			
Single pulse forward current	I _{FSM}		150	Α		
Maximum repetitive forward current	I _{FRM}		60			
Maximum navvey discipation	Б	T _C = 25 °C	74	W		
Maximum power dissipation	P_{D}	T _C = 100 °C	29	VV		
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C		

VS-HFA15TB60SPbF

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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-	
		I _F = 15 A		-	1.3	1.7	V
Maximum forward voltage	V_{FM}	I _F = 30 A	See fig. 1	-	1.5	2.0	
		I _F = 15 A, T _J = 125 °C		-	1.2	1.6	
Maximum reverse		$V_R = V_R$ rated		-	1.0	10	
leakage current	I _{RM}	$T_J = 125 ^{\circ}\text{C}, V_R = 0.8 \text{x} V_R \text{rated}$	See fig. 2	-	400	1000	μΑ
Junction capacitance	C _T	V _R = 200 V See fig. 3		-	25	50	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body		-	8.0	-	nH

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CON	NDITIONS	MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A}$	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		23	-	
Reverse recovery time See fig. 5	t _{rr1}	T _J = 25 °C		-	50	60	ns
occ lig. o	t _{rr2}	T _J = 125 °C	I _F = 15 A	-	105	120	
Peak recovery current See fig. 6	I _{RRM1}	T _J = 25 °C		-	4.5	6.0	Α
	I _{RRM2}	T _J = 125 °C		-	6.5	10	_ ^
Reverse recovery charge	everse recovery charge Q_{rr1} $T_J = 25 ^{\circ}C$ $dI_F/dt = 200 A/\mu s$		-	84	180	nC	
See fig. 7	Q _{rr2}	T _J = 125 °C	V _R = 200 V	-	241	600	IIC
Peak rate of fall of recovery current during t _b See fig. 8	dI _{(rec)M} /dt1	T _J = 25 °C		-	188	-	- A/µs
	dI _{(rec)M} /dt2	T _J = 125 °C		-	160	-	Ανμδ

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	MBOL TEST CONDITIONS MIN. TYP.			MAX.	UNITS	
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Thermal resistance, junction to case	R _{thJC}	R _{thJC}		-	1.7	K/W	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	N/W	
Weight			-	2.0	-	g	
vveignt			-	0.07	-	oz.	
Marking device		Case style D ² PAK HFA15TB60S					





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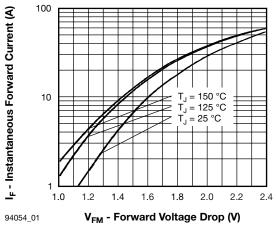


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

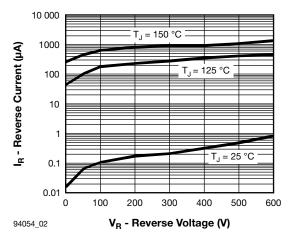


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

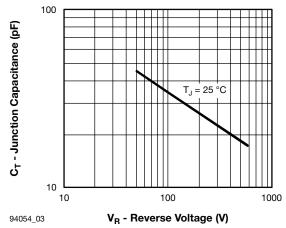


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

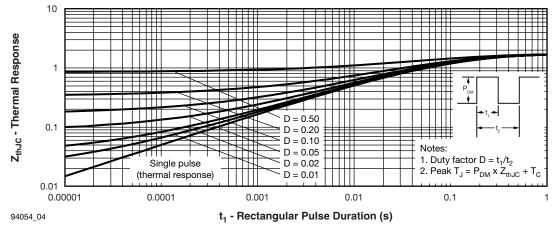


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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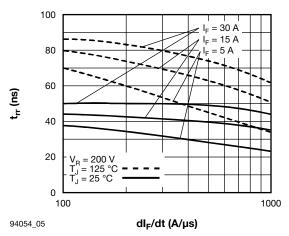


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt

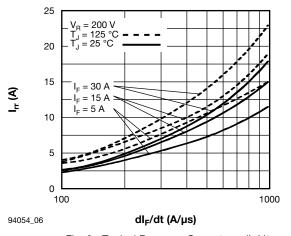


Fig. 6 - Typical Recovery Current vs. dI_F/dt

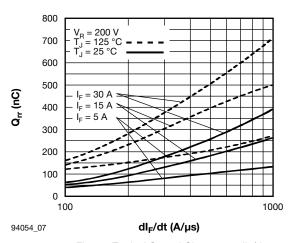


Fig. 7 - Typical Stored Charge vs. dI_F/dt

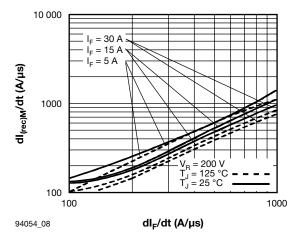


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt



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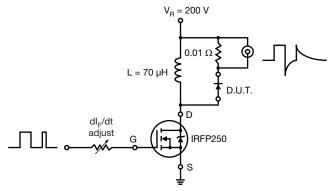
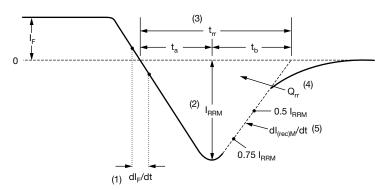


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_{rr}$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dl_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

VS-HFA15TB60SPbF

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ORDERING INFORMATION TABLE

Device code

vs-	HF	A	15	ТВ	60	S	TRL	PbF
1	2	3	4	5	6	7	8	9

- 1 HPP product suffix
- 2 HEXFRED® family
- 3 Process designator: A = Electron irradiated
- 4 Current rating (15 = 15 A)
- 5 Package outline (TB = TO-220, 2 leads)
- 6 Voltage rating (60 = 600 V)
- $7 S = D^2PAK$
- None = Tube (50 pieces)
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 9 PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95046</u>					
Part marking information	www.vishay.com/doc?95054				
Packaging information	www.vishay.com/doc?95032				
SPICE model	www.vishay.com/doc?95357				

www.vishay.com

For technical questions, contact: diodestech@vishay.com



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